NSN 5961-01-216-5323

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-216-5323 **Inclosure Material:** Glass **Overall Length:** 4.2 millimeters **Terminal Length:** 26.0 millimeters **Overall Diameter:** 1.0 millimeters **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 reverse voltage, peak and 30.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 360.00 milliamperes source cutoff current peak and 120.00 milliamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: